

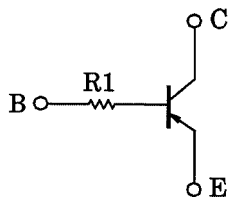
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2110,RN2111

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1110, RN1111

Equivalent Circuit



Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-100	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

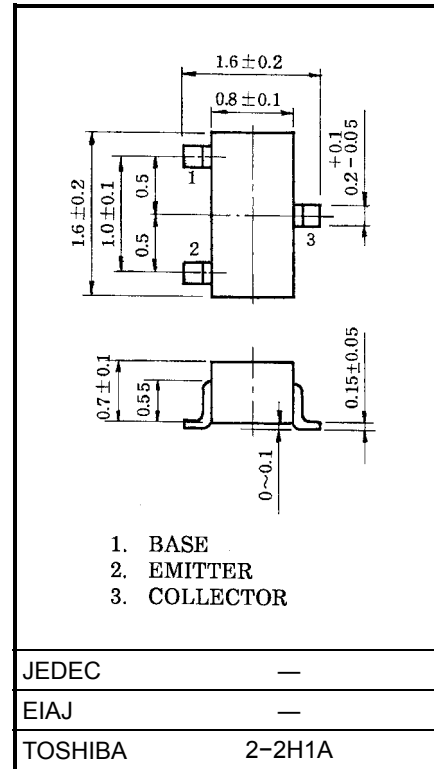
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	—	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
Emitter cut-off current	I_{EBO}	—	$V_{EB} = -5V, I_C = 0$	—	—	-100	nA
DC current gain	h_{FE}	—	$V_{CE} = -5V, I_C = -1mA$	120	—	400	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	$I_C = -5mA, I_B = -0.25mA$	—	-0.1	-0.3	V
Transition frequency	f_T	—	$V_{CE} = -10V, I_C = -5mA$	—	200	—	MHz
Collector output capacitance	C_{ob}	—	$V_{CB} = -10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input resistor	RN2110	R1	—	3.29	4.7	6.11	kΩ
	RN2111			7	10	13	

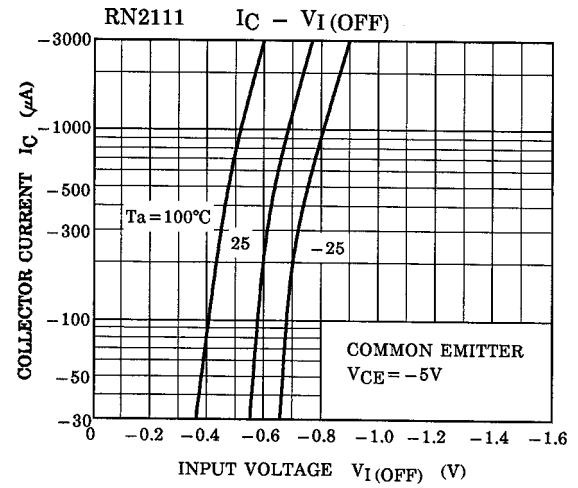
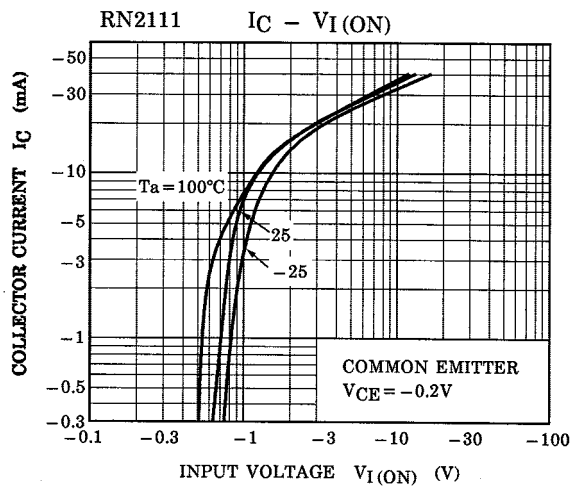
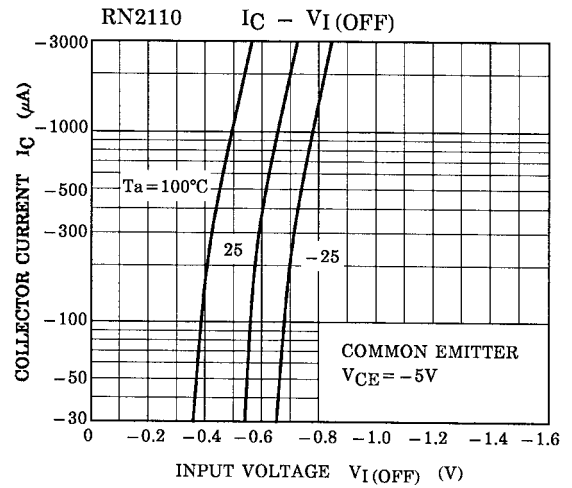
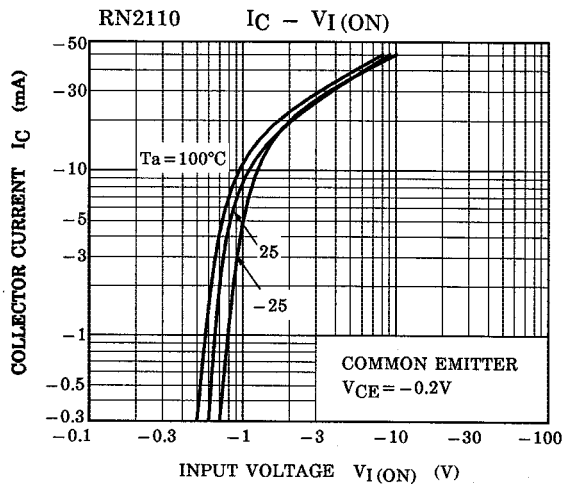
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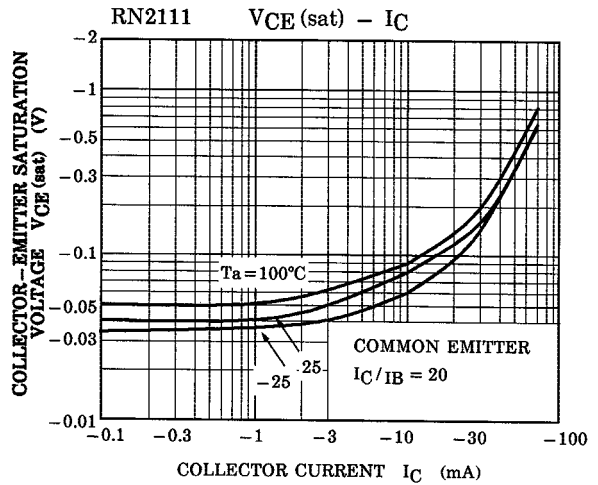
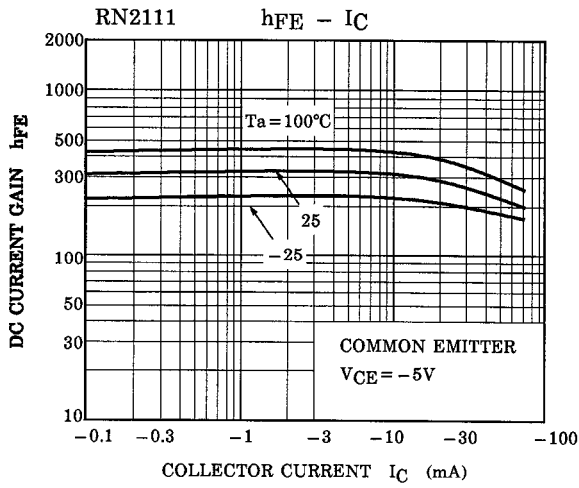
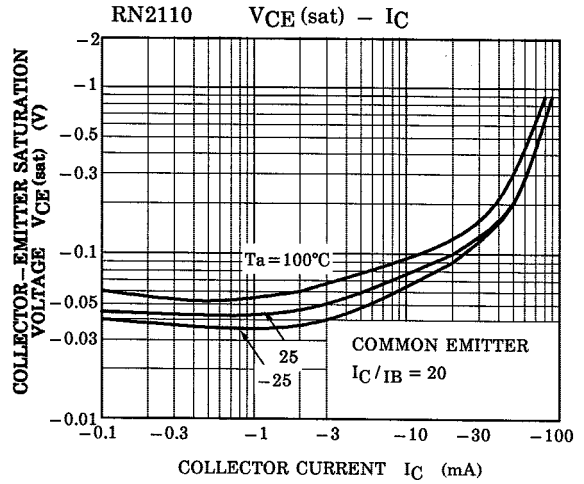
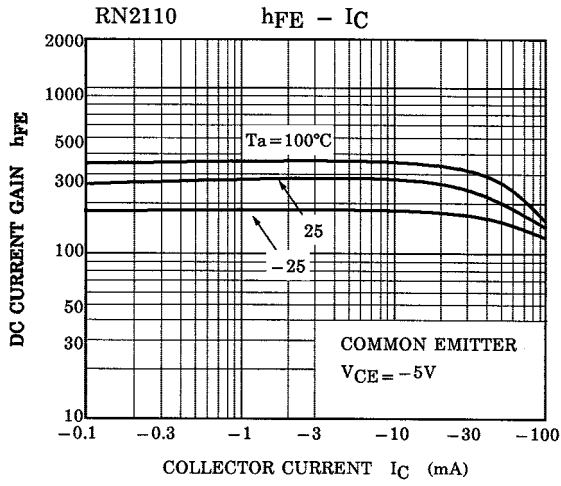
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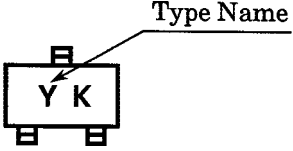
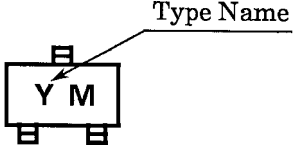
Unit in mm



Weight: 2.4mg





Type Name	Marking
RN2110	 <p>The diagram shows a rectangular component with four pins. The top pin is labeled with a small square symbol. The bottom two pins are also labeled with small square symbols. The letters 'Y K' are printed inside the rectangle. A line points from the text 'Type Name' to the 'Y' character.</p>
RN2111	 <p>The diagram shows a rectangular component with four pins. The top pin is labeled with a small square symbol. The bottom two pins are also labeled with small square symbols. The letters 'Y M' are printed inside the rectangle. A line points from the text 'Type Name' to the 'Y' character.</p>